MoS₂-wrapped silicon nanowires for photoelectrochemical water reduction

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ABSTRACT

Integration of molybdenum disulfide (MoS₂) onto high surface area photocathodes is highly desired to minimize the overpotential for the solar-powered hydrogen evolution reaction (HER). Semiconductor nanowires (NWs) are beneficial for use in photoelectrochemistry because of their large electrochemically available surface area and inherent ability to decouple light absorption and the transport of minority carriers. Here, silicon (Si) NW arrays were employed as a model photocathode system for MoS₂ wrapping, and their solar-driven HER activity was evaluated. The photocathode is made up of a well-defined MoS₂/TiO₂/Si coaxial NW heterostructure, which yielded photocurrent density up to 15 mA/cm² (at 0 V vs. the reversible hydrogen electrode (RHE)) with good stability under the operating conditions employed. This work reveals that earth-abundant electrocatalysts coupled with high surface area NW electrodes can provide performance comparable to noble metal catalysts for photocathodic hydrogen evolution.

1 Introduction

The vision of utilization of hydrogen as a future energy source requires a sustainable, highly efficient, and cost-effective production method [1]. To use renewable energy to produce hydrogen fuel, solar-driven water splitting is one of the most promising approaches [2, 3]. Effective photelectrochemical (PEC) water splitting devices must be able to absorb a large fraction of incident sunlight, generate high photocurrent with sufficient photovoltage, and exhibit long-term stability. One challenge in designing such a device is to reduce the reaction overpotential, by increasing the reaction kinetics on the surface. While existing noble metal catalysts, such as Pt, are highly active at catalyzing the hydrogen evolution reaction (HER) [4, 5], the high cost

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of these materials limits the economic viability of their use for hydrogen production. The intensive search for earth-abundant, inexpensive, and nontoxic catalysts with comparable performance for the HER has led to significant progress in the development of new catalysts, including metal alloys [6, 7], nitrides [8], borides [9], carbides [9, 10], chalcogenides [11–16], and phosphides [17]. In particular, metal chalcogenides, such as molybdenum sulfide (MoS_x) , are an exciting group of HER catalysts that exhibit promising activity in both crystalline and amorphous forms, as well as in the form of grafted molecular clusters [11, 12, 18–20]. Despite the considerable efforts dedicated to investigating and optimizing the catalytic activity of various MoS_x materials, the effective integration of MoS_x onto photocathodes is still a challenge. To achieve high geometric area-normalized HER activity, it is necessary to carefully engineer MoS_x functional nanostructures to maximize the density of active sites, which have been identified both theoretically [21, 22] and experimentally [11, 12, 23, 24] to be the uncoordinated sulfur edge sites.

High surface area photoelectrodes, such as semiconductor nanowire (NW) arrays, are attractive because of their large semiconductor/electrolyte interfacial area, enhanced light scattering effect, and efficient transport of charge carriers [25–27]. Silicon (Si), with bandgap of 1.12 eV, is a promising candidate as a lightabsorber due to its relatively low cost, excellent carrier transport properties, and suitable band edge with respect to HER potential [27]. As atomically thin MoS₂ has limited light absorption, the successful integration of MoS₂ with semiconductor NWs constitutes an ideal system for PEC hydrogen production.

In this work, using a p-Si NW array as scaffold, a well-defined MoS₂/TiO₂/Si NW integrated coaxial heterostructure was constructed as a model photocathode system for PEC hydrogen generation. Multilayer MoS₂ with a small domain size of ~10 nm was uniformly wrapped on the surface of the NWs, exposing a high density of active uncoordinated edge sites. An onset of photocurrent at ~0.30 V vs. the reversible hydrogen electrode (RHE), together with a short-circuit current density of 15 mA/cm² under simulated 1 sun illumination was achieved. Additionally, this functional device exhibits good stability under the operating conditions employed. This system demonstrates the principle that earth-abundant electrocatalysts coupled with high surface area NW electrodes can provide performance comparable to noble metal catalysts for photocathodic hydrogen evolution. This principle could serve as a guide for future studies in the field of solar-powered chemical fuel production, by offering an additional dimension for device engineering through the benefits of the NW morphology.

2 Results and discussion

Since metal oxide overlayers can assist in preserving the photoresponse of Si [28], in our study Si/TiO₂ core–shell structures were prepared via atomic layer deposition (ALD) of 30 nm of crystalline TiO₂ on the NW surface at 573 K. The MoS₂ layer was synthesized by thermolysis of ammonium tetrathiomolybdate ((NH₄)₂MoS₄) at low temperature [29, 30]. (NH₄)₂MoS₄ was dissolved in an organic solvent and drop-casted onto the NW surface (additional details are provided in the Electronic Supplementary Material (ESM)). After drop-casting, the coated NWs were annealed at 573–673 K in a N₂/H₂ (80/20 sccm) atmosphere at ambient pressure to form MoS₂.

A single TiO₂/Si NW wrapped with MoS₂ was characterized by high-angle annular dark field (HAADF) imaging (Fig. 1(a)). The MoS₂ and TiO₂ shells appear brighter, as Ti and Mo atoms located in the shell have a higher atomic number than the Si atoms in the core. High-resolution transmission electron microscopy (HRTEM) revealed multiple layers of MoS₂ on the NW surface, as evidenced by the lattice fringes with a spacing of 0.62 nm, in agreement with the expected MoS₂ interlayer distance of 0.614 nm (Fig. 1(b)) [31, 32]. The crystallinity of MoS₂ depends strongly on the annealing temperature, with increasing temperature resulting in higher crystallinity (Fig. S1 in the ESM). Although the surface is mostly covered with MoS₂ basal planes, the domain size is smaller than 10 nm and abundant crystal edges of MoS₂ are evident (indicated by the red arrows in Fig. 1(b)). Relative to MoS₂ coated on planar electrode surfaces [18, 33], this core-shell structure exposes more MoS_2 edges because of the large surface area afforded by the NW morphology. Further analysis of the elemental



Figure 1 (a) HAADF image of the $MoS_2/TiO_2/Si$ coaxial structure on a single NW. (b) HRTEM image taken at the MoS_2/TiO_2 interface as shown in the green box of (a). The lattice fringes show a spacing of 0.62 nm between adjacent layers, which is in agreement with the expected MoS_2 interlayer distance. The red arrows indicate the edge of a MoS_2 cluster where HER-active MoS_2 edge sites are likely exposed on the NW surface. (c)–(f) EDS elemental mapping along a single NW, which shows the elemental distribution of (c) Si, (d) Ti, (e) Mo, and the combined signal of (f) Mo/Ti/Si, demonstrating the well-defined integrated coaxial heterostructure of $MoS_2/TiO_2/Si$ NW.

distribution was obtained from energy dispersive X-ray spectroscopy (EDS) mapping. The elemental map shows a homogenous distribution of Si in the core (Fig. 1(c)), Ti in the inner shell (Fig. 1(d)), and a thin layer of Mo in the outer shell (Fig. 1(e)). The combined elemental mapping in Fig. 1(f) demonstrates a well-defined coaxial heterostructure of MoS₂/TiO₂/Si along a single NW. The uniform coating of MoS₂ distributes the solar-generated electron flux evenly along the semiconductor light-absorber. The effective utilization of the high surface area of the NW decreases the surface flux of electrons, leading to a reduced HER kinetic overpotential.

Additional characterization was performed to understand the nature of the synthesized MoS_{2r} from which deeper insight into the performance may be gained. Thermolysis of $(NH_4)_2MoS_4$ at low temperature in the presence of H_2 will result in the conversion initially to MoS_3 and finally to MoS_2 [29]. X-ray photoelectron spectroscopy (XPS) (Fig. 2) and Raman



Figure 2 XPS characterization of (a) Mo and (b) S signals in the MoS_x cocatalyst before and after annealing. The Mo 3d region shows the Mo oxidation state is 4+ before and after annealing while the S 2p region shows a transition from MoS_3 to MoS_2 .

spectroscopy (Fig. S2 in the ESM) were used to investigate the chemical states of Mo and S before and after annealing. The binding energy of the Mo 3d_{5/2} photoelectron peak remained constant (229.2 eV) before and after annealing, indicating a 4+ oxidation state for Mo [13]. The S 2p region of MoS_x before annealing shows two doublets, consistent with that seen for MoS₃ amorphous catalysts [13]. The doublet at lower binding energy (162.2 and 163.4 eV) is attributed to S2- at the basal plane, characteristic of MoS_2 . The doublet at higher binding energy (163.8 and 165.0 eV) is attributed to S_2^{2-} at the bridge sites. After annealing, only the doublet at lower binding energy corresponding to MoS₂ is observed. These results demonstrate that this low temperature annealing process is a simple method for the synthesis of stoichiometric MoS₂ catalysts with small domain sizes and uniform coverage, even on highly corrugated surfaces.

The electrocatalytic performance of MoS₂ layers

was first evaluated using planar p⁺-Si substrate as an electrode. Different volumes of precursor solution, corresponding to different loadings of the MoS_2 cocatalyst, were drop-casted onto the electrode surface, followed by annealing at 673 K in a N_2/H_2 atmosphere at ambient pressure. The TiO₂ interlayer was required to achieve stable current; otherwise, the underlying Si will be gradually oxidized, leading to a decrease in activity (Fig. S3 in the ESM). The catalytic performance was measured using iR-compensated linear scan voltammetry in 0.5 M H_2SO_4 electrolyte in a three-electrode configuration. Onset of cathodic current was

observed at approximately -0.20 V vs. the reversible hydrogen electrode (RHE) (Fig. 3(a)). The cathodic current increased with increasing loading of MoS₂ and exhibited a Tafel slope of 75–84 mV per decade (Fig. 3(b)). The apparent exchange current densities j_0 were obtained from the Tafel plots and are summarized in Table S1 (in the ESM). The Tafel slope observed here compares favorably with MoS₂ synthesized by chemical vapor deposition (CVD) on glassy carbon electrodes [18, 34]. After evaluating the dependence of HER activity on the MoS₂ loading density, the optimal condition was applied to the NW



Figure 3 (a) and (b) Electrochemical performance of MoS_2 catalysts in 0.5 M H₂SO₄: (a) Linear sweep voltammograms and (b) Tafel plots for TiO₂-coated p⁺-Si planar surface with different MoS_2 loadings. (c) 45° tilt and (d) cross-sectional SEM images of as-grown Si NW arrays. (e) Comparison of HER performance (under 100 mW/cm² simulated AM 1.5 G irradiation) of Si NW array photocathodes coated with MoS_2 to an MoS_2 coated planar Si substrate, and a Si NW array loaded with Pt nanoparticles. (f) Spectral response (incident photon to current conversion efficiency (IPCE)) of Si NW arrays after coating with MoS_2 layers.

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photoelectrodes for subsequent PEC investigation.

To evaluate the impact of MoS₂ cocatalyst deposition on the solar-to-hydrogen activity of the Si NW photocathodes, PEC measurements were performed under the same conditions as the electrochemical measurements described above. A well-defined high surface area Si NW array electrode was fabricated via deep reactive ion etching (DRIE) (experimental details are provided in the ESM). The scanning electron micrographs are shown in Fig. 3(c) and 3(d). The etched NW arrays are approximately 30 µm in length and 800 nm in diameter, and are arranged on a square lattice with periodicity of 2 µm. In order to achieve a positive photovoltage, a heavily doped n⁺ emitter layer was diffused into the surface region of Si NWs via rapid temperature annealing at 1173 K for 3 min, using arsenic (As) as an n-type dopant. Following the procedure outlined above, a MoS₂/TiO₂/ n⁺p-Si NW coaxial heterostructure was created from the Si NW array. For comparison, Pt/TiO₂/n⁺p-Si NW was also fabricated by sputtering Pt nanoparticles onto the NW surface (Fig. S4 in the ESM). The PEC performance of these photoelectrodes was tested under identical conditions, using 100 mW/cm² simulated AM 1.5 G irradiation. Figure 3(e) shows the activity comparison of Si photocathodes before and after deposition of MoS₂. Si NW arrays exhibit nearly no photo-activity in the absence of a cocatalyst. When MoS₂ was deposited onto the NW surface, the onset of photocurrent shifted substantially to a more positive potential (~0.30 V vs. RHE), only 100 mV cathodic of the Pt nanoparticle decorated electrode. For the affordable application of overall water splitting by coupling of dual light absorbers, a current density on the order of 10 mA/cm^2 is necessary [20]. The MoS₂ layers wrapped Si NW array photocathode provides a current density of ~15 mA/cm² at 0 V vs. RHE, indicating that this photocathode can be an affordable integrated water-splitting system.

To study the impact of NW surface area on the required catalytic activity, an equal loading of MoS_2 was deposited on the surface of a planar TiO_2/n^+p -Si electrode. As shown in Fig. 3(e), the photo-activity was substantially improved in the Si NW array, indicating that increasing the surface area will decrease

the surface flux of electrons, leading to a lower requirement for the catalytic activity on the surface. Figure 3(f) shows the typical spectral response for $MoS_2/TiO_2/n^+p$ -Si NWs (experimental details are provided in the ESM). The external quantum efficiency reaches a maximum at 500 nm, consistent with the external quantum efficiency observed for Si wires coated with a thin layer of Pt nanoparticles [4]. The maximum external quantum efficiency is larger than 0.75, ~25% higher than previously reported for Ni–Mo coated Si wire arrays [7].

Another important criterion for PEC energy conversion is the long-term stability of the photoelectrode under actual operating conditions. The short-term stability of the coaxial MoS₂/TiO₂/Si NW structure and its faradaic efficiency for hydrogen reduction were evaluated by chronoamperometry. The potential of the photocathode was held at -0.33 V vs. RHE under 100 mW/cm² simulated AM 1.5 G irradiation, and both the photocurrent and hydrogen gas concentration in the Ar carrier gas were monitored. Bubbles were continuously evolved from photocathode, and the accumulation and release of these bubbles led to the observed variations in photocurrent over the duration of the measurement. The photocurrent of the coaxial MoS₂/TiO₂/Si NW structure remained at approximately 21 mA/cm² for 75 min without degradation (Fig. 4), and the faradaic efficiency for hydrogen evolution to H₂ was found to be ~100% (more details are provided in the ESM and Fig. S5). This result shows that the coaxial MoS₂/TiO₂/Si NWs are stable and are indeed reducing water into H₂.



Figure 4 Stability test of MoS_2 wrapped Si NW array. Current vs. time during the controlled potential photoelectrolysis under 100 mW/cm² simulated AM 1.5 G irradiation at -0.33 V vs. RHE.

3 Conclusions

This work shows the feasibility of functionalizing a Si NW array photocathode with a MoS₂ cocatalyst to drive solar hydrogen production. The exploration of the earth-abundant catalyst MoS₂ and its application in high surface area Si NW array electrodes establishes a general strategy to replace precious metal cocatalysts for efficient and affordable solar-to-fuel application at a large scale.

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